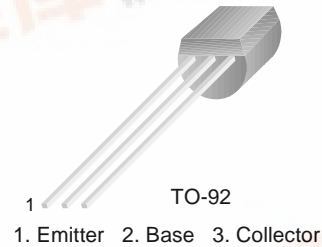


FAIRCHILD
SEMICONDUCTOR®

KSP62/63/64

Darlington Transistor

- Collector-Emitter Voltage: V_{CES} =KSP62: 20V
KSP63/64: 30V
- Collector Power Dissipation: P_C (max)=625mW



PNP Epitaxial Silicon Darlington Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage : KSP62 : KSP63/64	-20 -30	V V
V_{CEO}	Collector-Emitter Voltage : KSP62 : KSP63/64	-20 -30	V V
V_{EBO}	Emitter-Base Voltage	-10	V
I_C	Collector Current	-500	mA
P_C	Collector Power Dissipation	625	mW
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55~150	$^\circ\text{C}$

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV_{CES}	Collector-Emitter Breakdown Voltage : KSP62 : KSP63/64	$I_C = -100\mu\text{A}$, $I_B = 0$	-20 -30		V V
I_{CBO}	Collector Cut-off Current : KSP62 : KSP63/64	$V_{CB} = -15\text{V}$, $I_E = 0$ $V_{CB} = -30\text{V}$, $I_E = 0$		-100 -100	nA nA
I_{EBO}	Emitter Cut-off Current	$V_{BE} = -10\text{V}$, $I_C = 0$		-100	nA
h_{FE}	* DC Current Gain : KSP62 : KSP63 : KSP64 : KSP63 : KSP64	$V_{CE} = -5\text{V}$, $I_C = -10\text{mA}$ $V_{CE} = -5\text{V}$, $I_C = -100\text{mA}$	20K 5K 10K 10K 20K		
$V_{CE}(\text{sat})$	* Collector-Emitter Saturation Voltage : KSP62 : KSP63/64	$I_C = -10\text{mA}$, $I_B = -0.01\text{mA}$ $I_C = -100\text{mA}$, $I_B = -0.1\text{mA}$		-1.0 -1.5	V V
$V_{BE}(\text{on})$	* Base-Emitter On Voltage : KSP62 : KSP63/64	$V_{CE} = -5\text{V}$, $I_C = -10\text{mA}$ $V_{CE} = -5\text{V}$, $I_C = -100\text{mA}$		-1.4 -2	V V
f_T	Current Gain Bandwidth Product : KSP63/64	$V_{CE} = -5\text{V}$, $I_C = -100\text{mA}$ $f = 100\text{MHz}$	125		MHz

* Pulse Test: $PW \leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

Typical Characteristics

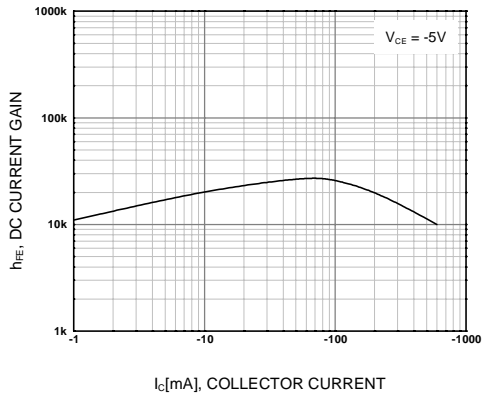


Figure 1. DC current Gain

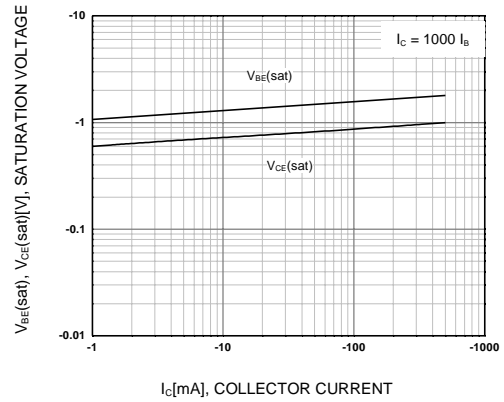


Figure 2. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

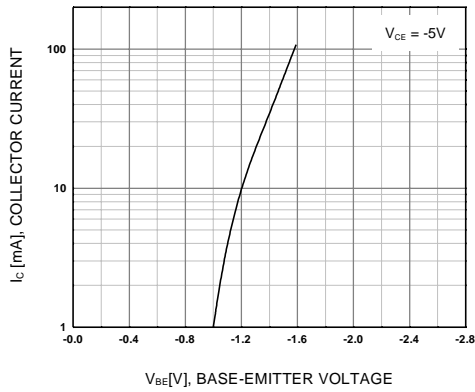


Figure 3. Base-Emitter On Voltage

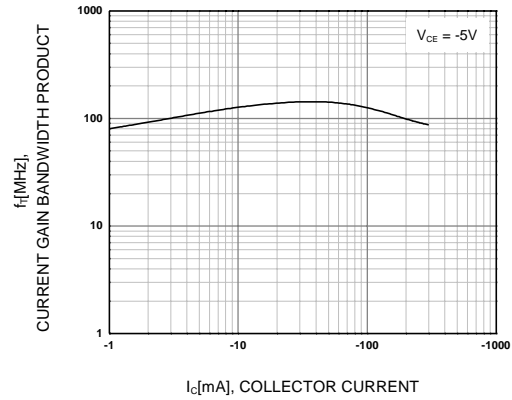
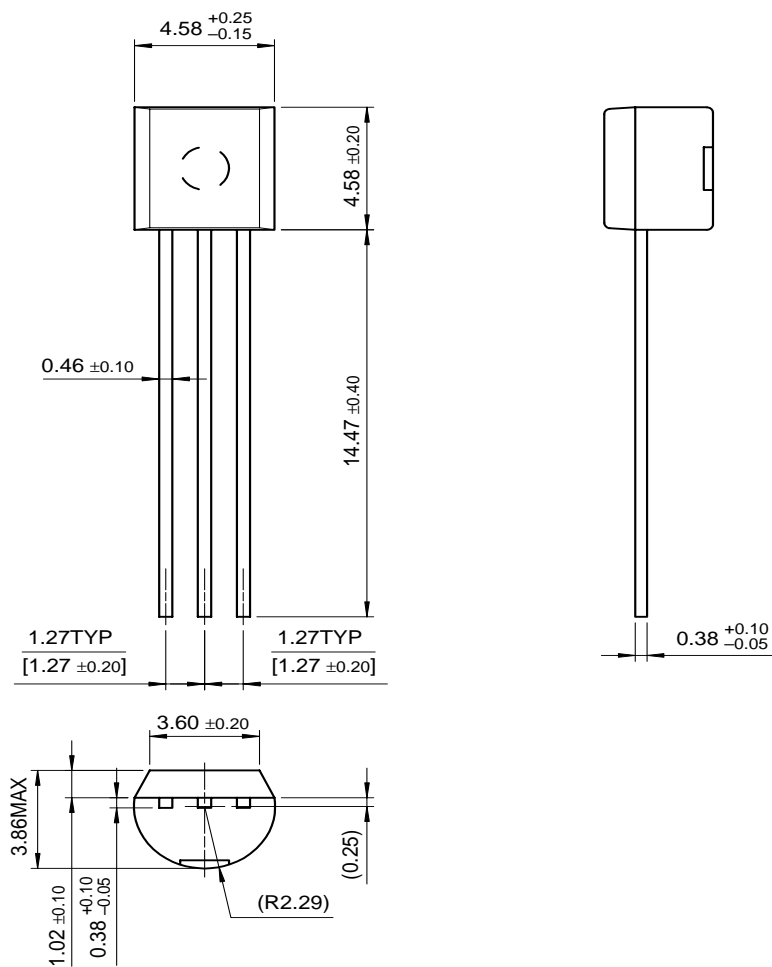


Figure 4. Current Gain Bandwidth Product

Package Dimensions

TO-92



Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench®	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOMET™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
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EnSigna™	I ² C™	OCX™	RapidConfigure™	UHC™
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Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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PRODUCT STATUS DEFINITIONS

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